Validation Die

Product Die

Leveraging 3D-IC for On-chip Timing Uncertainty Measurements

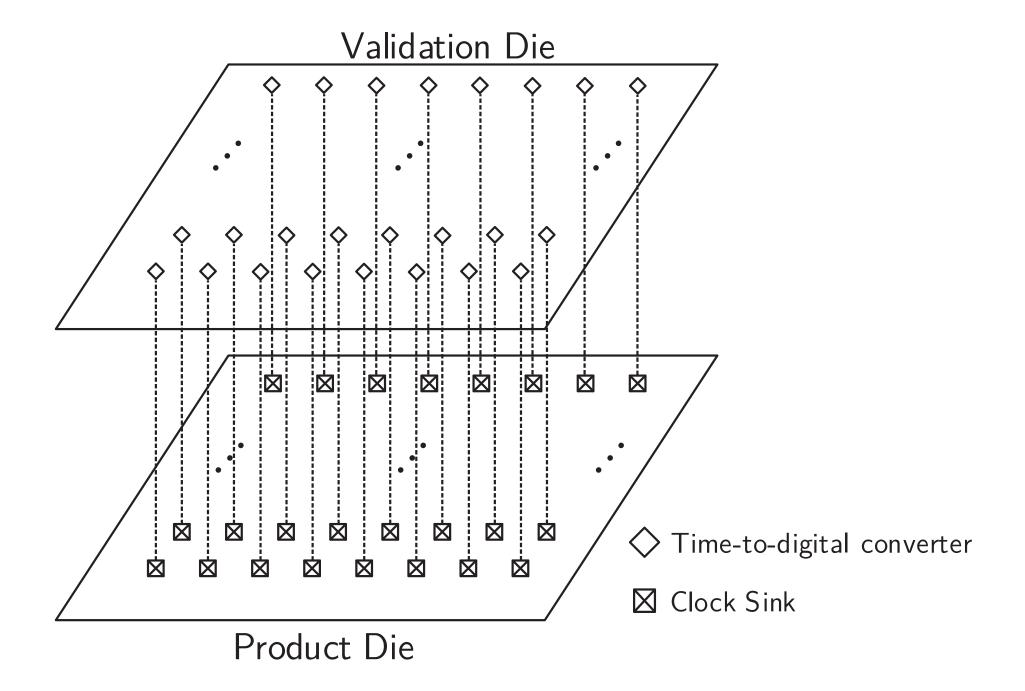
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Introduction

Abstract

Modern high-performance designs require accurate on-chip timing uncertainty measurements for post-silicon validation of high speed interfaces and clock distribution networks. These measurements are facilitated by on-chip timing sensors, which incur area, routing, and power overhead.

With increasing design complexity and process variations, post-silicon validation and debug capabilities must keep up accordingly to meet competitive product time-to-market. However, enhancing post-silicon validation and debug capabilities cannot simply be met by proliferating on-chip structures, since the overhead would be prohibitively expensive.



Solution

Move validation structures onto a separate die which would be stacked onto the product die.

The cost of die stacking would be justified by reducing the product die area or by accelerating silicon debug and validation for faster time-to-market.

Advantages

- Enhanced On-chip Timing Observability
- Reduced Area Overhead
- Noise Isolation

Methodology

- 1. TDC
- Sub-gate delay measurement resolution
- Low Power
- Small Area
- 2. Clock sink selection
- 3. Inter-die vias assignment
- 4. Reference signal for indirect skew measurement

Clock Skew

Clock skew is measured by comparing different DUT clocks to a reference signal. The DUT clock and the reference signal are sent down the leading and lagging inverter chain respectively. The sampling flip-flop chain indicates how long the leading edge have propagated before the lagging edge arrives. Afterwards, the sampled signals are processed by the edge detection logic and latched into the accumulation flip-flops when triggered by the Sample signal. This Sample signal could be generated by delaying the reference signal for the edge detection logic propagation delay, or independently. The time between the reference edge and the DUT clock edge is indicated by multiplying the number of consecutive zeros with the Vernier delay line resolution. The skew between two clock sinks is finally calculated by comparing the outputs of its TDCs.

Circuit Implementation Reference Signal Leading Reference TDC 1 Inverter Chain DUT clock Sampling Flip-flops Reference Signal Lagging Inverter Chain DUT clock Sink Edge Location Detector Sticky Logic Sticky Mode Accumulation Sample signal Flip-flops DUT clock Scan clock

Reference Signal Clock Sink A TDC 1 Measurement Clock Sink B TDC 2 Measurement Time Area & Power

Clock Jitter

Jitter measurement is launched by setting the circuit to sticky mode and feeding the DUT clock into three inputs: the leading inverter chain, the lagging inverter chain and the clock buffer for the accumulation flip-flop chain. The changing location of edges indicates jitter. By asserting the sticky mode signal, the worst case jitter is recorded by the accumulation flip-flop chain. Jitter measurement is concluded by switching the circuit into scan-out mode.

Physical Implementation

Technology	Area	Power	Energy
130nm	16,931 µm2	2.11339 mW	1.057 pJ

Measurement results for an implementation of the TDC architecture which contains 150 inverters in each delay line, sampling and accumulation flip-flops, and processing logic.

Power consumption measured is for jitter measurements is assuming input clock frequency of 2 GHz.

Energy consumption measured is listed for a one-shot skew measurement.

Input: sg_l : List of sink groups

Die Stack Configuration

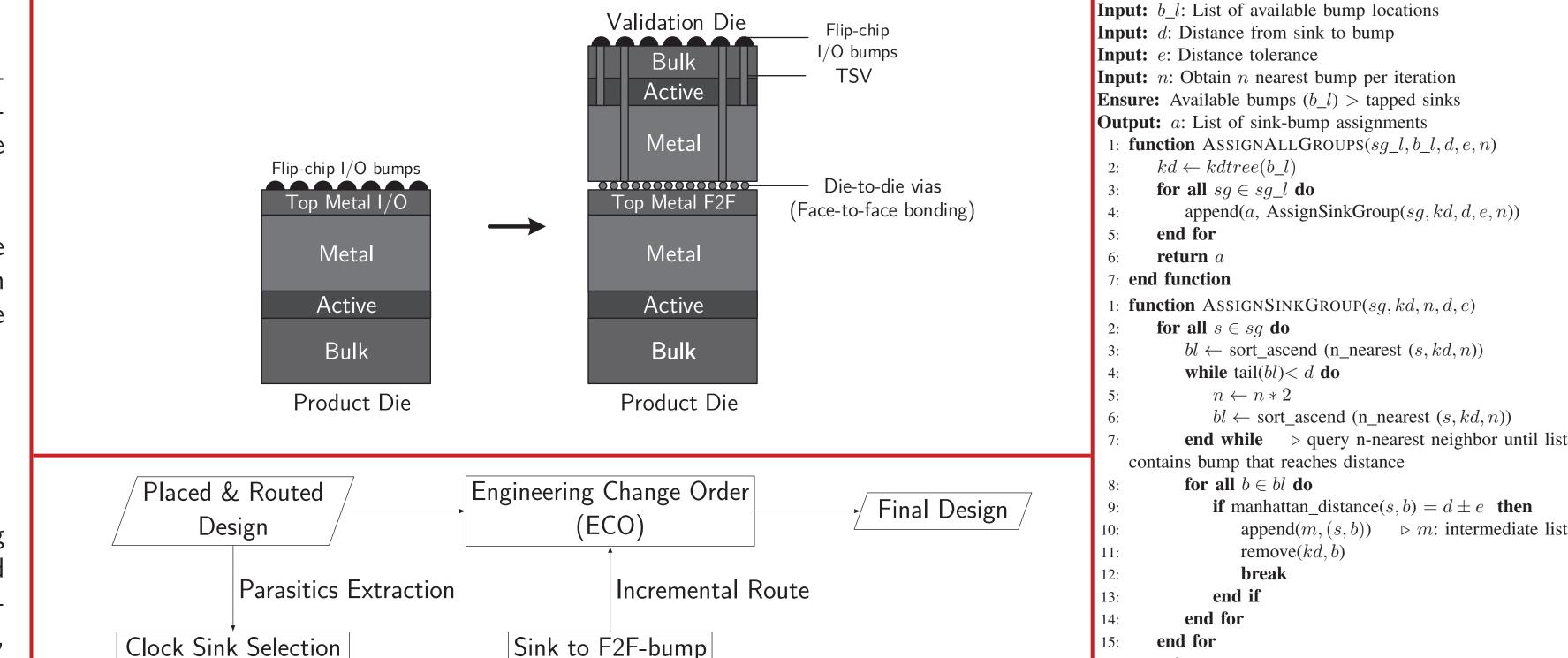
Face-to-Face (F2F): F2F bondpoints have negligible delay parasitics, hence allowing onchip timing measurements without imposing additional measurement offsets. F2F bondpoints commonly have 10-25 µm [6] pitch, hence providing fast, high throughput interface between the product and validation die.

For tier assignment, the validation die would be designated as the tier with its substrate thinned for I/O connections. This assignment is to avoid modifications to the design on the product die. The product die would then have its I/O connections routed through the F2F bondpoints, along with additional signals of interest for debug and validation.

Design Flow

The physical design challenges include selecting which clock sinks to probe and assigning those selected sinks to available bondpoints/bumps. The design flow starts with a placed and routed design with its parasitic extracted. This is to ensure we obtain clock sink insertion delay analysis that are as accurate as possible. After the initial place and route step, the available bondpoints are those that are not reserved for routing the product's I/Osignals in both die stack configurations shown on the right.

The bump assignment step considers the interconnect delay between the clock sink its assigned F2F bump. If the parasitic delay matches between two TDCs, hence the difference of both outputs would indicate actual skew. Otherwise, the parasitic delay must be de-embedded from the measurement readings. One way to avoid characterizing and deembedding parasitic delay is to match the wire delay between a selected clock sink and its assigned bump.



Assignment

Matching wire delays could be achieved through custom routing or wire delay matching. Without custom routing, we approximate wire delay by calculating the Manhattan/ rectilinear distance between a selected sink with a candidate bump, and then verify with parasitic extraction. In a scenario where the assignment fails due to available bump constraint, the designer could prioritize selected sinks into groups.

Bump Assignment

- k-d tree [7]: Fast nearest available bump search
- Specify sink groups for priority assignment.
- Specify distance and range.
- Algorithm finds nearest available bump to each sink
- Sink-to-bump assignments are incrementally routed with ECO.

17: end function

References

Available F2F-bumps

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